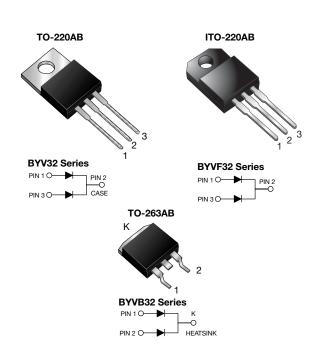


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Vishay General Semiconductor

RoHS

Dual Common-Cathode Ultrafast Rectifier



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|----------------------------------|--|--|--|--|
| I _{F(AV)} | 18 A | | | | |
| V _{RRM} | 50 V to 200 V | | | | |
| I _{FSM} | 150 A | | | | |
| t _{rr} | 25 ns | | | | |
| V _F | 0.85 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | TO-220AB, ITO-220AB, TO-263AB | | | | |
| Diode variations | Common cathode | | | | |

FEATURES

- Power pack
- · Glass passivated chip junction
- Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commerical grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | | |
|--|-----------------------------------|---------------|-----------|-----------|-----------|------|--|
| PARAMETER | SYMBOL | BYV32-50 | BYV32-100 | BYV32-150 | BYV32-200 | UNIT | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | ٧ | |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 105 | 140 | ٧ | |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 150 | 200 | V | |
| Maximum average forward rectified current at T _C = 125 °C | I _{F(AV)} | 18 | | | | Α | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 150 | | | Α | | |
| Operating storage and temperature range | T _J , T _{STG} | - 65 to + 150 | | | °C | | |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min | V _{AC} | 1500 | | | V | | |



BYV32-xxx, BYVF32-xxx, BYVB32-xxx

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | | |
|---|---|-------------------------|--------------------|---|--|-----------|------|----|
| PARAMETER | TEST CO | NDITIONS | SYMBOL | OL BYV32-50 BYV32-100 BYV32-150 BYV32-2 | | BYV32-200 | UNIT | |
| Maximum instantaneous | I _F = 20 A | T _J = 25 °C | V _E (1) | 1.15 | | | | V |
| forward voltage per diode | _F = 5.0 A | T _J = 100 °C | V _F (') | 0.85 | | | | |
| Maximum DC reverse | | T _J = 25 °C | | 10 | | | | μА |
| current per diode at rated DC blocking voltage | | T _J = 100 °C | I _R | 600 | | | | |
| Maximum reverse recovery time per diode | I _F = 1 A, V _R = 30 V dl/dt = 100 A/µs, I _{rr} = 10 % I _{RM} | | t _{rr} | 25 | | | | ns |
| Typical junction capacitance per diode | 4.0 V, 1 MHz |) V, 1 MHz | | 45 | | | pF | |

Note

 $^{^{(1)}}$ Pulse test: 300 μs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|----------------|-----|------|------|------|--|
| PARAMETER | SYMBOL | BYV | BYVF | BYVB | UNIT | |
| Typical thermal resistance from junction to case per diode | $R_{	heta JC}$ | 1.6 | 5.0 | 1.6 | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | BYV32-200-E3/45 | 1.85 | 45 | 50/tube | Tube | | |
| ITO-220AB | BYVF32-200-E3/45 | 1.97 | 45 | 50/tube | Tube | | |
| TO-263AB | BYVB32-200-E3/45 | 1.35 | 45 | 50/tube | Tube | | |
| TO-263AB | BYVB32-200-E3/81 | 1.35 | 81 | 800/reel | Tape and reel | | |
| TO-220AB | BYV32-200HE3/45 (1) | 1.85 | 45 | 50/tube | Tube | | |
| ITO-220AB | BYVF32-200HE3/45 (1) | 1.97 | 45 | 50/tube | Tube | | |
| TO-263AB | BYVB32-200HE3/45 (1) | 1.35 | 45 | 50/tube | Tube | | |
| TO-263AB | BYVB32-200HE3/81 (1) | 1.35 | 81 | 800/reel | Tape and reel | | |

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

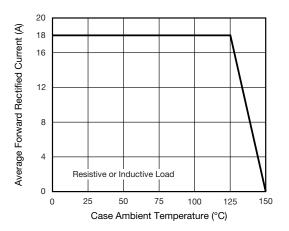


Fig. 1 - Forward Current Derating Curve

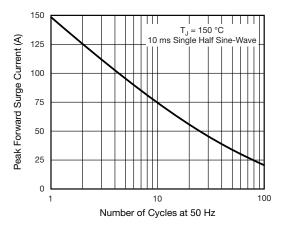


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

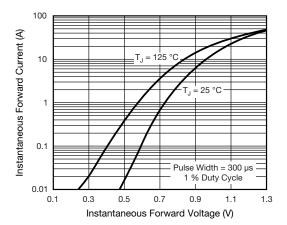


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

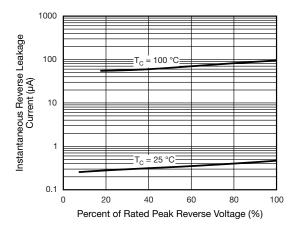


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

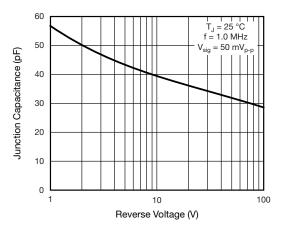
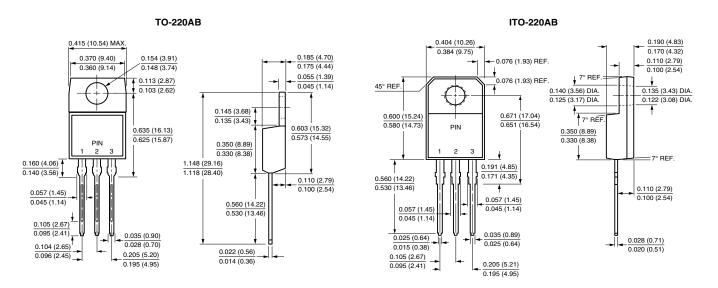


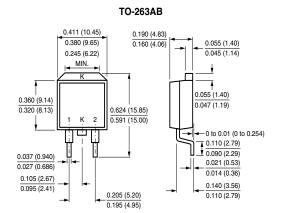
Fig. 5 - Typical Junction Capacitance Per Diode



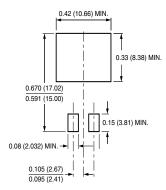
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Mounting Pad Layout





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